Spec. No. : HL200708 Issued Date : 2007.04.01 Revised Date : 2009.03.24

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# HSR120 thru HSR1100

Schottky Barrier Rectifiers (Reverse Voltage 20 to 100V, Forward Current 1A)

## **Features**

- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

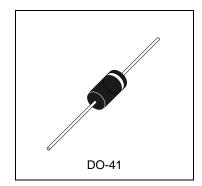


- Cases: DO-41 molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: Color band denotes cathode end
- High temperature soldering guaranteed: 250°C/10seconds/.375"(9.5mm) lead lengths at 5lbs.,(2.3kg) tension
- Weight: 0.35gram



Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load. Derate current by 20%.

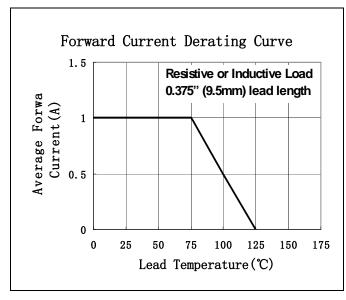
Ratings	Symbol	HSR 120	HSR 130	HSR 140	HSR 150	HSR 160	HSR 180	HSR 1100	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	80	100	V
Surge Peak Reverse Voltage	V <sub>RSM</sub>	14	21	28	35	42	57	71	V
DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	80	100	V
Average Forward Rectified Current (T <sub>A</sub> =75°C)	I <sub>FAV</sub>	1							Α
Peak Forward Surge Current, 50Hz Half Sine-wave (T <sub>A</sub> =25°C)	I <sub>FSM</sub>	40							Α
Repetitive Peak Forward C (f>15Hz)	I <sub>FRM</sub>	12							Α
Instantaneous Forward Voltage	V <sub>F</sub>	0.48	3 0.52 0.65 0.8				.8	V	
Leakage Current (T <sub>J</sub> =25°C, V <sub>R</sub> =V <sub>RRM</sub> )	1_	0.1							mA
Leakage Current (T <sub>J</sub> =100°C, V <sub>R</sub> =V <sub>RRM</sub> )	· I <sub>R</sub>	10							mA
Typical Junction Capacitance	Сл	170							pF
Rating for Fusing, t<10ms (T <sub>A</sub> =25°C)	i <sup>2</sup> t	12.5							A <sup>2</sup> s
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	30							°C/W
Thermal Resistance Junction to Lead	$R_{\theta JL}$	15							°C/W
Operating Junction Temperature Range	TJ	-65 to +125							°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150							°C
ESD Protection Voltage	V <sub>ESD</sub>	12							KV

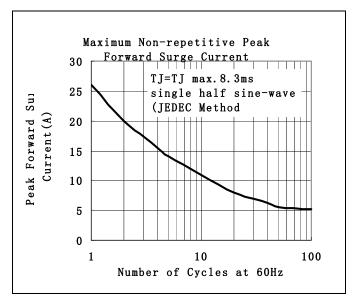


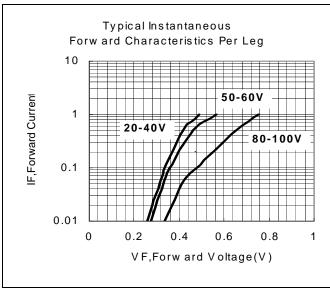
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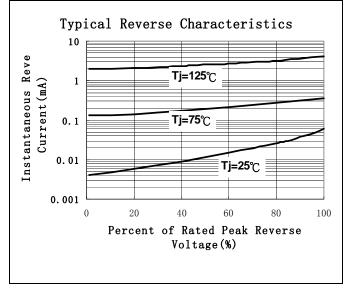
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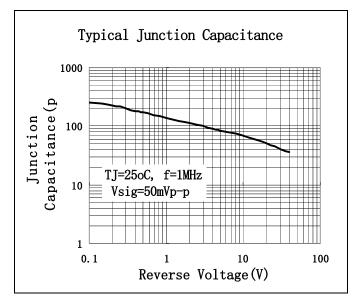
# **Characteristics Curve**

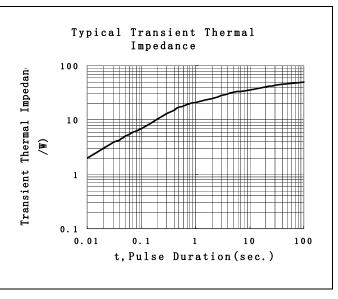








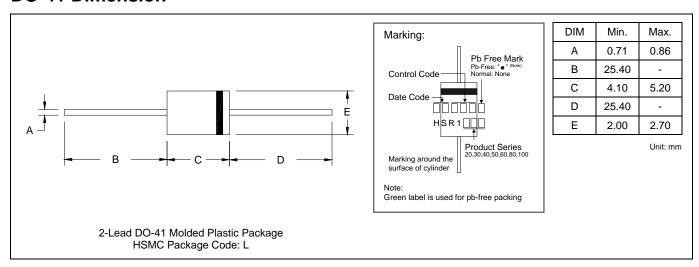




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### **DO-41 Dimension**



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